

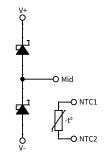
1700 V, 600 A, Silicon Carbide, Half-Bridge Rectifier

$V_{_{\mathrm{R}}}$	1700 V
I _F	600 A

Technical Features

- Ultra-Low Loss, High Frequency Operation
- Low Forward Voltage (V_F) Drop with Positive Temperature Coefficient
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Temperature-Independent Switching Behavior





Applications

- Railway, Traction, and Motor Drives
- EV Chargers
- High-Efficiency Converters / Inverters
- Renewable Energy
- Smart-Grid / Grid-Tied Distributed Generation

System Benefits

- Enables Compact, Lightweight Systems
- Increased System Efficiency, due to Low Switching & Conduction Losses of SiC
- Reduced Thermal Requirements and System Cost

Maximum Parameters (Verified by Design)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions	Note
Maximum Reverse Voltage	V _{R-Max}			1700	V		
Continuous Formand Comment			986			T _C = 25°C, T _{VJ} ≤ 175°C	
Continuous Forward Current	I _F		702			T _C = 90°C, T _{VJ} ≤ 175°C	
Maximum Pulsed Forward Current	I _{F (Pulsed)}			1200	A	t_{Pmax} limited by T_{VJmvax} $T_C = 25$ °C	
Maximum Virtual Junction Temperature	T _v ,	-40		175	°C		

Diode Characteristics (Per Position) ($T_{VJ} = 25$ °C unless otherwise specified)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions	Note
Die de Famus ad Velta es	.,		1.6		V	I _F = 600 A	
Diode Forward Voltage	V _F		2.2			I _F = 600 A, T _{VJ} = 175°C	
December Comment			0.06		mA	V _R = 1700 V, T _{VJ} = 25°C	
Reverse Current	I _R		0.29			V _R = 1700 V, T _{VJ} = 175°C	
Total Capacitive Charge	Qc		4.9		mC	V _R = 1100 V	
			55.7			V _R = 0 V, f = 100 kHz	
Total Capacitance	С		2.9	nF	nF	V _R = 550 V, f = 100 kHz	
			2.7			V _R = 1100 V, f = 100 kHz	
Thermal Resistance, Junction to Case	R _{TH-JC}		0.048			Per position	

Note:

¹SiC Schottky diodes are majority carrier devices, so there is no reverse recovery charge.

Module Physical Characteristics

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Package Resistance, M1 (High-Side)	R ₁₋₂		106.5		0	T _c = 125°C, Note 1
Package Resistance, M2 (Low-Side)	R ₂₋₃		126.3		μΩ	T _c = 125°C, Note 1
Stray Inductance	L _{Stray}		4.9		nH	Between DC- and DC+, f = 10 MHz
Case Temperature	T _c	-40		125	°C	
		3	4.5	5	N-m	Baseplate, M6 bolts
Mounting Torque	Ms	0.9	1.1	1.3		Power Terminals, M4 bolts
Weight	W		167		g	
Case Isolation Voltage	V _{isol}	4			kV	AC, 50 Hz, 1 minute
Comparative Tracking Index	СТІ	600				
Classica Distance		13.07				Terminal to Terminal
Clearance Distance		6.00				Terminal to Heatsink
Creepage Distance		14.27			mm	Terminal to Terminal
		12.34				Terminal to Heatsink

NTC Characteristics (T_{NTC} = 25 °C unless otherwise specified)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Notes
Resistance at 25°C	R ₂₅		4700		Ω	
Tolerance of R ₂₅			±1		%	
Beta Value for 25°C to 85°C	B _{25/85}		3435		K	
Beta Value for 0°C to 100°C	B _{0/100}		3399		K	
Tolerance of B _{25/85}			±1		%	
Maximum Power Dissipation	P _{Max}		50		mW	

Steinhart & Hart Coefficients for NTC Resistance & NTC Temperature Computation (T in K)

$$\ln\left(\frac{R}{R_{25}}\right) = A + \frac{B}{T} + \frac{C}{T^2} + \frac{D}{T^3}$$

$$\ln\left(\frac{R}{R_{25}}\right) = A + \frac{B}{T} + \frac{C}{T^2} + \frac{D}{T^3}$$

$$\frac{1}{T} = A_1 + B_1 \ln\left(\frac{R}{R_{25}}\right) + C_1 \ln^2\left(\frac{R}{R_{25}}\right) + D_1 \ln^3\left(\frac{R}{R_{25}}\right)$$

A ₁	B ₁	C ₁	D_1
3.354E-03	3.001E-04	5.085E-06	2.188E-07

Typical Performance

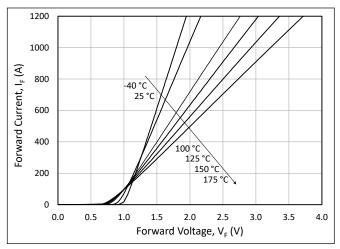


Figure 1. Typical Forward Characteristics

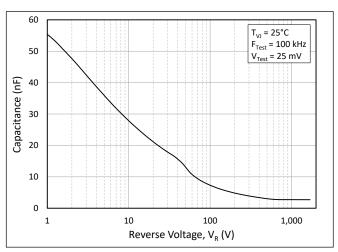


Figure 3. Typical Capacitance vs. Reverse Voltage

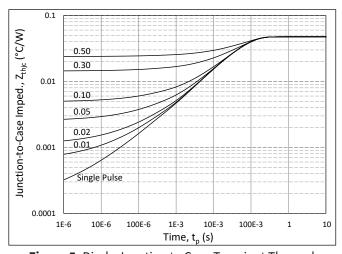


Figure 5. Diode Junction to Case Transient Thermal Impedance, $Z_{th JC}$ (°C/W)

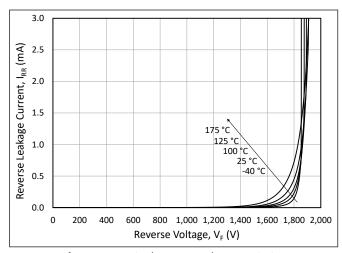


Figure 2. Typical Reverse Characteristics

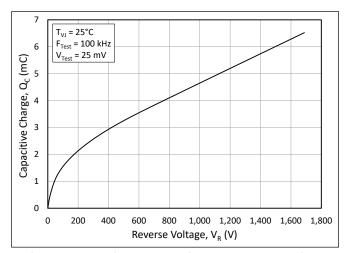


Figure 4. Typical Capacitive Charge vs. Reverse Voltage

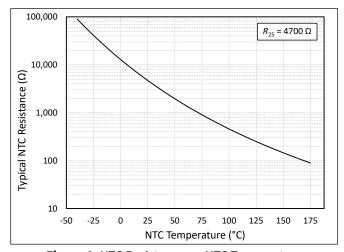
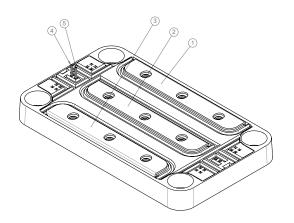
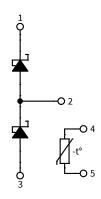


Figure 6. NTC Resistance vs. NTC Temperature

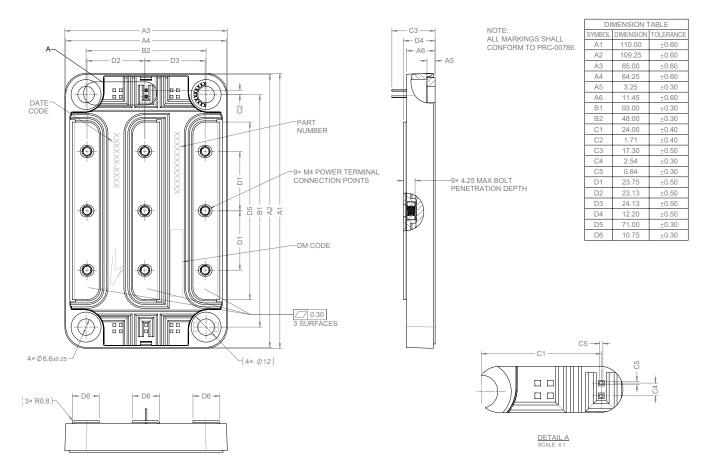
Schematic and Pin Out



PIN OUT SCHEME					
PIN	LABEL				
1	V+				
2	Mid				
3	V-				
4	NTC1				
(5)	NTC2				
	11102				



Package Dimension (mm)



Supporting Links & Tools

Evaluation Tools & Support

- CAR600M17HN6 PLECS Model
- SpeedFit 2.0 Design Simulator™
- Technical Support Forum

Application Notes

- CPWR-AN35: 62mm Thermal Interface Material Application Note
- CPWR-AN39: KIT-CRD-CIL12N-HM User Guide

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